

#### **Features and Benefits**

- Low R<sub>DS(ON)</sub> outputs
- Internal mixed current decay mode
- Synchronous rectification for low power dissipation
- Internal UVLO
- Crossover-current protection
- 3.3 and 5 V compatible logic supply
- Thin profile QFN and TSSOP packages
- Thermal shutdown circuitry
- Short-to-ground protection
- Shorted load protection
- Low current Sleep mode, < 10 μA</li>

#### Package:



24-pin TSSOP with exposed thermal pad (LP Package)



Approximate size

#### Description

The A4986 is a dual DMOS full-bridge stepper motor driver with parallel input communication and overcurrent protection. Each full-bridge output is rated up to 35 V and  $\pm 2$  A.

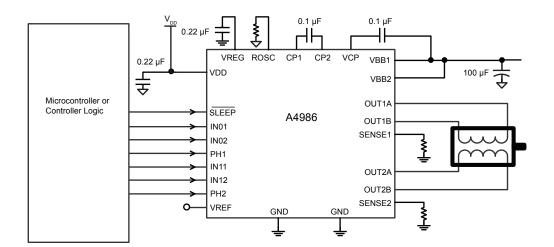
The A4986 includes fixed off-time pulse width modulation (PWM) current regulators, along with 2- bit nonlinear DACs (digital-to-analog converters) that allow stepper motors to be controlled in full, half, and quarter steps. The PWM current regulator uses the Allegro® patented mixed decay mode for reduced audible motor noise, increased step accuracy, and reduced power dissipation.

Internal synchronous rectification control circuitry is provided to improve power dissipation during PWM operation.

The outputs are protected from shorted load and short-to-ground events, which protect the driver and associated circuitry from thermal damage or flare-ups. Other protection features include thermal shutdown with hysteresis, undervoltage lockout (UVLO) and crossover current protection. Special power-up sequencing is not required.

The A4986 is supplied in a 24-pin TSSOP (LP) with exposed thermal pad for enhanced thermal performance. It has a 0.65 pitch and an overall package height of  $\leq$ 1.2 mm. It is lead (Pb) free, with 100% matte tin leadframe plating.

## **Typical Application Diagram**



## A4986

# DMOS Dual Full-Bridge PWM Motor Driver with Overcurrent Protection

#### **Selection Guide**

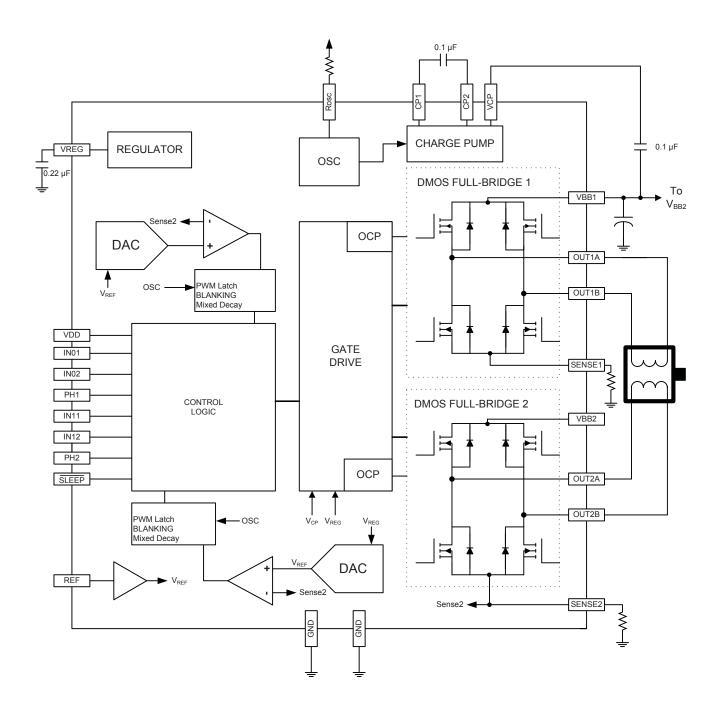
Part Number	Package	Packing		
A4986SLPTR-T	24-pin TSSOP with exposed thermal pad	4000 pieces per 13-in. reel		

#### **Absolute Maximum Ratings**

Characteristic	Symbol	Notes	Rating	Units
Load Supply Voltage	V <sub>BB</sub>		35	V
Output Current	I <sub>OUT</sub>		±2	А
Logic Input Voltage	V <sub>IN</sub>		-0.3 to 5.5	V
Logic Supply Voltage	V <sub>DD</sub>		-0.3 to 5.5	V
VBBx to OUTx			35	V
Sense Voltage	V <sub>SENSE</sub>		0.5	V
Reference Voltage	V <sub>REF</sub>		5.5	V
Operating Ambient Temperature	T <sub>A</sub>	Range S	-20 to 85	°C
Maximum Junction	T <sub>J</sub> (max)		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to 150	°C



### **Functional Block Diagram**



## A4986

# DMOS Dual Full-Bridge PWM Motor Driver with Overcurrent Protection

### **ELECTRICAL CHARACTERISTICS**<sup>1</sup> at $T_A = 25$ °C, $V_{BB} = 35$ V (unless otherwise noted)

Characteristics	Symbol	Test Conditions	Min.	Typ. <sup>2</sup>	Max.	Units
Output Drivers	1	1	1	l		
Load Supply Voltage Bange	\/	Operating	8	_	35	V
Load Supply Voltage Range	V <sub>BB</sub>	During Sleep Mode	0	-	35	V
Logic Supply Voltage Range	V <sub>DD</sub>	Operating	3.0	_	5.5	V
Output On Resistance	D	Source Driver, I <sub>OUT</sub> = -1.5 A	_	320	430	mΩ
Output On Resistance	R <sub>DSON</sub>	Sink Driver, I <sub>OUT</sub> = 1.5 A	_	320	430	mΩ
Body Diode Forward Voltage	V <sub>F</sub>	Source Diode, I <sub>F</sub> = -1.5 A	_	_	1.3	V
Body Blode Folward Voltage	v <sub>F</sub>	Sink Diode, I <sub>F</sub> = 1.5 A	_	_	1.3	V
		f <sub>PWM</sub> < 50 kHz	_	_	4	mA
Motor Supply Current	I <sub>BB</sub>	Operating, outputs disabled	_	_	2	mA
		Sleep Mode	_	_	10	μA
		f <sub>PWM</sub> < 50 kHz	_	_	8	mA
Logic Supply Current	I <sub>DD</sub>	Outputs off	_	_	5	mA
		Sleep Mode	_	-	10	μA
Control Logic						
Logic Input Voltage	V <sub>IN(1)</sub>		V <sub>DD</sub> ×0.7	_	_	V
Logic input voitage	V <sub>IN(0)</sub>		_	_	V <sub>DD</sub> ×0.3	V
Logic Input Current	I <sub>IN(1)</sub>	$V_{IN} = V_{DD} \times 0.7$	-20	<1.0	20	μΑ
Logic input Current	I <sub>IN(0)</sub>	$V_{IN} = V_{DD} \times 0.3$	-20	<1.0	20	μΑ
Logic Input Pull-down	R <sub>IN02</sub>		_	100	_	kΩ
Logic Input Full-down	R <sub>IN12</sub>		_	50	_	kΩ
Logic Input Hysteresis	V <sub>HYS(IN)</sub>	As a % of V <sub>DD</sub>	5	11	19	%
Blank Time	t <sub>BLANK</sub>		0.7	1	1.3	μs
Fixed Off-Time		OSC = VDD or GND	20	30	40	μs
Fixed Oil-Tillie	t <sub>OFF</sub>	$R_{OSC} = 25 \text{ k}\Omega$	23	30	37	μs
Reference Input Voltage Range	V <sub>REF</sub>		0	_	4	V
Reference Input Current	I <sub>REF</sub>		-3	0	3	μΑ
	err <sub>l</sub>	V <sub>REF</sub> = 2 V, %I <sub>TripMAX</sub> = 33.3%	_	-	±15	%
Current Trip-Level Error <sup>3</sup>		V <sub>REF</sub> = 2 V, %I <sub>TripMAX</sub> = 66.7%	_	_	±5	%
		V <sub>REF</sub> = 2 V, %I <sub>TripMAX</sub> = 100.00%	_	_	±5	%
Crossover Dead Time	t <sub>DT</sub>		100	475	800	ns
Protection						
Overcurrent Protection Threshold	I <sub>OCPST</sub>		2.1	_	_	Α
Thermal Shutdown Temperature	T <sub>TSD</sub>		_	165	_	°C
Thermal Shutdown Hysteresis	T <sub>TSDHYS</sub>		_	15	_	°C
VDD Undervoltage Lockout	V <sub>DDUVLO</sub>	V <sub>DD</sub> rising	2.7	2.8	2.9	V
VDD Undervoltage Hysteresis	V <sub>DDUVLOHYS</sub>		_	90	_	mV

<sup>&</sup>lt;sup>1</sup>For input and output current specifications, negative current is defined as coming out of (sourcing) the specified device pin.



<sup>&</sup>lt;sup>2</sup>Typical data are for initial design estimations only, and assume optimum manufacturing and application conditions. Performance may vary for individual units, within the specified maximum and minimum limits.

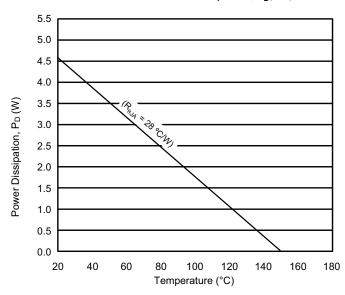
 $<sup>^{3}</sup>V_{ERR} = [(V_{REF}/8) - V_{SENSE}] / (V_{REF}/8).$ 

#### THERMAL CHARACTERISTICS may require derating at maximum conditions

Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance	$R_{\theta JA}$	LP package; on 4-layer PCB, based on JEDEC standard	28	°C/W

<sup>\*</sup>In still air. Additional thermal information available on Allegro Web site.

#### Maximum Power Dissipation, P<sub>D</sub>(max)





### **Functional Description**

**Device Operation.** The A4986 is designed to operate one stepper motor in full, half, or quarter step mode. The currents in each of the output full-bridges, all N-channel DMOS, are regulated with fixed off-time pulse width modulated (PWM) control circuitry. Each full-bridge peak current is set by the value of an external current sense resistor,  $R_{Sx}$ , and a reference voltage,  $V_{REFx}$ .

Percentages of the peak current are set using a 2-bit nonlinear DAC that programs 33%, 66%, or 100% of the peak current, or disables the outputs.

Internal PWM Current Control. Each full-bridge is controlled by a fixed off-time PWM current control circuit that limits the load current to a desired value, I<sub>TRIP</sub>. Initially, a diagonal pair of source and sink FET outputs are enabled and current flows through the motor winding and the current sense resistor, R<sub>Sy</sub>. When the voltage across  $R_{Sx}$  equals the DAC output voltage, the current sense comparator resets the PWM latch. The latch then turns off the sink and source FETs.

The maximum value of current limiting is set by the selection of  $R_{Sx}$  and the voltage at the VREF pin. The transconductance function is approximated by the maximum value of current limiting,  $I_{TripMAX}$  (A), which is set by

$$I_{TripMAX} = V_{REF} / (8 \times R_S)$$

where  $R_S$  is the resistance of the sense resistor ( $\Omega$ ) and  $V_{REF}$  is the input voltage on the REF pin (V).

The 2-bit DAC output reduces the V<sub>REF</sub> output to the current sense comparator in precise steps, such that

$$I_{trip} = (\%I_{TripMAX}/100) \times I_{TripMAX}$$

It is critical that the maximum rating (0.5 V) on the SENSE1 and SENSE2 pins is not exceeded.

**Fixed Off-Time.** The internal PWM current control circuitry uses a one-shot circuit to control the duration of time that the DMOS FETs remain off. The off-time, t<sub>OFF</sub>, is determined by the ROSC terminal. The ROSC terminal has two settings:

- ROSC tied to VDD or ground off-time internally set to
- ROSC through a resistor to ground off-time is determined by the following formula

$$t_{OFF} \approx R_{OSC} / 825$$

Where  $t_{OFF}$  is in  $\mu s$ .

**Blanking.** This function blanks the output of the current sense comparators when the outputs are switched by the internal current control circuitry. The comparator outputs are blanked to prevent false overcurrent detection due to reverse recovery currents of the clamp diodes, and switching transients related to the capacitance of the load. The blank time, t<sub>BLANK</sub> (µs), is approximately

$$t_{\rm BLANK} \approx 1 \; \mu s$$

#### Shorted-Load and Short-to-Ground Protection.

If the motor leads are shorted together, or if one of the leads is shorted to ground, the driver will protect itself by sensing the overcurrent event and disabling the driver that is shorted, protecting the device from damage. In the case of a short-to-ground, the device will remain disabled (latched) until the SLEEP input goes high or VDD power is removed. A short-to-ground overcurrent event is shown in figure 1.

When the two outputs are shorted together, the current path is through the sense resistor. After the blanking time (≈1 µs) expires, the sense resistor voltage is exceeding its trip value, due to the overcurrent condition that exists. This causes the driver to go into a fixed off-time cycle. After the fixed off-time expires the driver turns on again and the process repeats. In this condition the driver is completely protected against overcurrent events, but the short is repetitive with a period equal to the fixed off-time of the driver. This condition is shown in figure 2.

If the driver is operating in Mixed decay mode, it is normal for the positive current to spike, due to the bridge going in the forward direction and also in the negative direction, as a result of the direction change implemented by the Mixed decay feature. This is shown in figure 3. In both instances the overcurrent circuitry is protecting the driver and prevents damage to the device.

Charge Pump (CP1 and CP2). The charge pump is used to generate a gate supply greater than that of VBB for driving the



source-side FET gates. A 0.1 µF ceramic capacitor, should be connected between CP1 and CP2. In addition, a 0.1 µF ceramic capacitor is required between VCP and VBB, to act as a reservoir for operating the high-side FET gates.

Capacitor values should be Class 2 dielectric  $\pm 15\%$  maximum, or tolerance R, according to EIA (Electronic Industries Alliance) specifications.

**V<sub>REG</sub>** (VREG). This internally-generated voltage is used to operate the sink-side FET outputs. The VREG pin must be decoupled with a 0.22  $\mu$ F ceramic capacitor to ground.  $V_{REG}$  is internally monitored. In the case of a fault condition, the FET outputs of the A4986 are disabled.

Capacitor values should be Class 2 dielectric ±15% maximum, or tolerance R, according to EIA (Electronic Industries Alliance) specifications.

**Shutdown.** In the event of a fault, overtemperature (excess T<sub>I</sub>) or an undervoltage (on VCP), the FET outputs of the A4986 are disabled until the fault condition is removed. At power-on, the UVLO (undervoltage lockout) circuit disables the FET outputs and resets the translator to the Home state.

**Sleep Mode (**SLEEP**).** To minimize power consumption when the motor is not in use, this input disables much of the internal circuitry including the output FETs, current regulator, and charge pump. A logic low on the SLEEP pin puts the A4986 into Sleep mode. When emerging from Sleep mode, in order to allow the charge pump to stabilize, provide a delay of 1 ms before issuing a logic command.

**Mixed Decay Operation.** The bridge operates in Mixed Decay mode, as shown in figures 5 through 7. As the trip point is reached, the A4986 initially goes into a fast decay mode for 31.25% of the off-time, t<sub>OFF</sub>. After that, it switches to Slow Decay mode for the remainder of t<sub>OFF</sub>. A timing diagram for this feature appears in figure 4.

Synchronous Rectification. When a PWM-off cycle is triggered by an internal fixed-off time cycle, load current recirculates in Mixed Decay mode. This synchronous rectification feature turns on the appropriate FETs during current decay, and effectively shorts out the body diodes with the low FET R<sub>DS(ON)</sub>. This reduces power dissipation significantly, and can eliminate the need for external Schottky diodes in many applications. Synchronous rectification turns off when the load current approaches zero (0 A), preventing reversal of the load current.

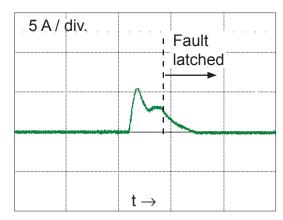


Figure 1. Short-to-ground event

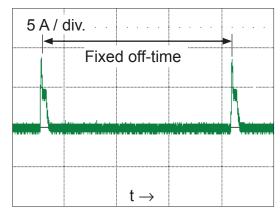


Figure 2. Shorted load (OUTxA → OUTxB) in Slow decay mode

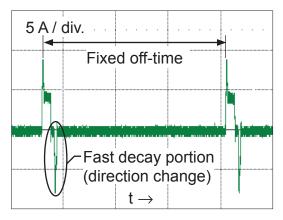
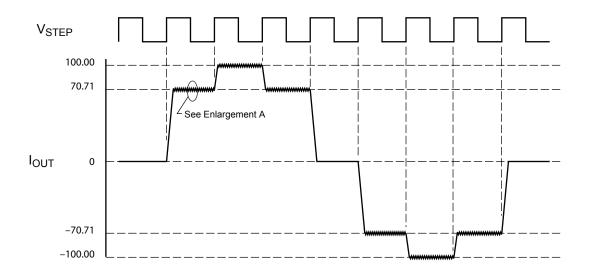
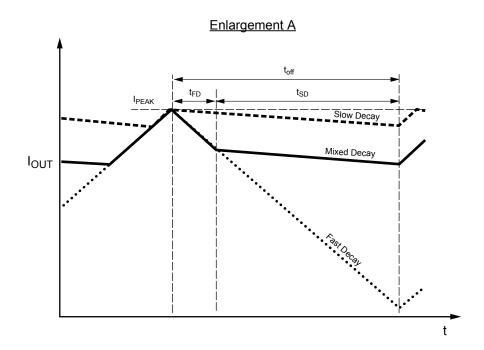


Figure 3. Shorted load (OUTxA → OUTxB) in Mixed decay mode

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Symbol	Characteristic			
t <sub>off</sub>	Device fixed off-time			
I <sub>PEAK</sub>	Maximum output current			
t <sub>SD</sub>	Slow decay interval			
t <sub>FD</sub>	Fast decay interval			
I <sub>OUT</sub>	Device output current			

Figure 4. Current Decay Modes Timing Chart

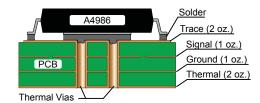


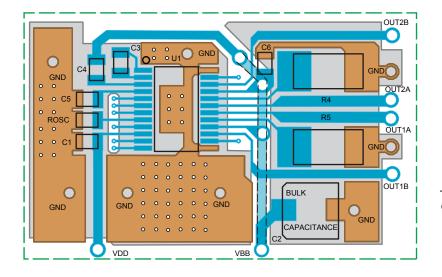
## **Application Layout**

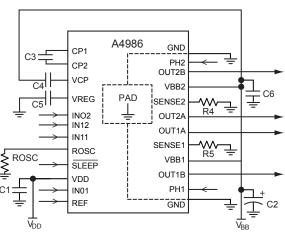
**Layout**. The printed circuit board should use a heavy ground-plane. For optimum electrical and thermal performance, the A4986 must be soldered directly onto the board. On the underside of the A4986 package is an exposed pad, which provides a path for enhanced thermal dissipation. The thermal pad should be soldered directly to an exposed surface on the PCB. Thermal vias are used to transfer heat to other layers of the PCB.

In order to minimize the effects of ground bounce and offset issues, it is important to have a low impedance single-point ground, known as a *star ground*, located very close to the device. By making the connection between the pad and the ground plane directly under the A4986, that area becomes an ideal location for a star ground point. A low impedance ground will prevent ground bounce during high current operation and ensure that the supply voltage remains stable at the input terminal.

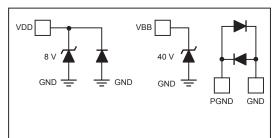
The two input capacitors should be placed in parallel, and as close to the device supply pins as possible. The ceramic capacitor (CIN1) should be closer to the pins than the bulk capacitor (CIN2). This is necessary because the ceramic capacitor will be responsible for delivering the high frequency current components. The sense resistors,  $R_{\rm Sx}$ , should have a very low impedance path to ground, because they must carry a large current while supporting very accurate voltage measurements by the current sense comparators. Long ground traces will cause additional voltage drops, adversely affecting the ability of the comparators to accurately measure the current in the windings. The SENSEx pins have very short traces to the  $R_{\rm Sx}$  resistors and very thick, low impedance traces directly to the star ground underneath the device. If possible, there should be no other components on the sense circuits.

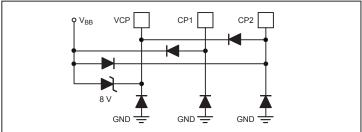


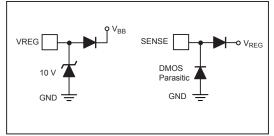


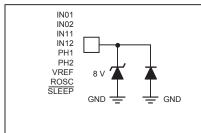


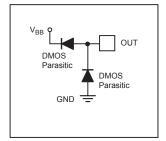
### Pin Circuit Diagrams



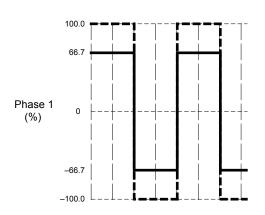


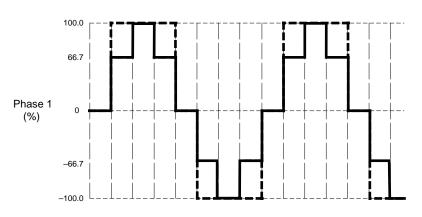


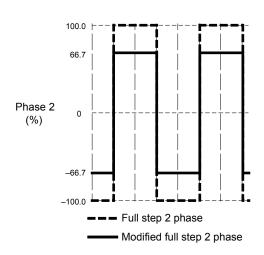




## Step Sequencing Diagrams







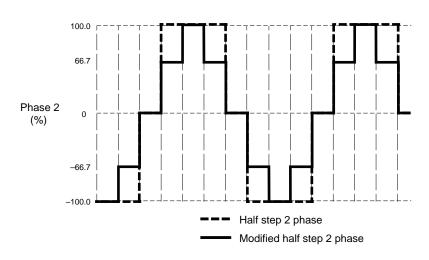
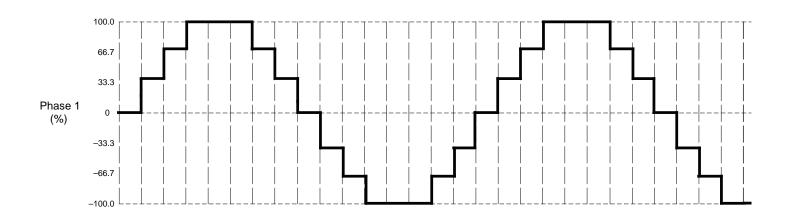


Figure 5. Step Sequencing for Full-Step Increments.

Figure 6. Step Sequencing for Half-Step Increments.



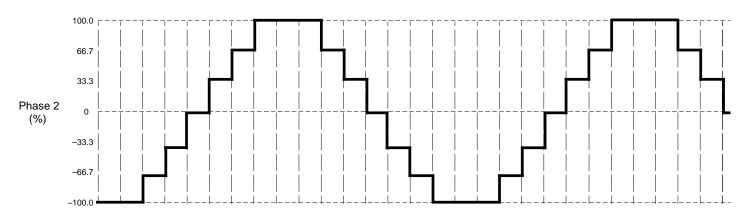


Figure 7. Step Sequence for Quarter-Step Increments

## **Step Sequencing Settings**

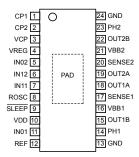
Full	1/2	1/4	Phase 1 (%I <sub>TripMax</sub> )	I0x	l1x	PHASE	Phase 2 (%I <sub>TripMax</sub> )	I0x	l1x	PHASE
	1	1	0	Н	Н	х	100	L	L	1
		2	33	L	Н	1	100	L	L	1
1	2	3	100/66*	L/H*	L	1	100/66*	L/H*	L	1
		4	100	L	L	1	33	L	Н	1
	3	5	100	L	L	1	0	Н	Н	Х
		6	100	L	L	1	33	L	Н	0
2	4	7	100/66*	L/H*	L	1	100/66*	L/H*	L	0
		8	33	L	Н	1	100	L	L	0
	5	9	0	Н	Н	Х	100	L	L	0
		10	33	L	Н	0	100	L	L	0
3	6	11	100/66*	L/H*	L	0	100/66*	L/H*	L	0
		12	100	L	L	0	33	L	Н	0
	7	13	100	L	L	0	0	Н	Н	Х
		14	100	L	L	0	33	L	Н	1
4	8	15	100/66*	L/H*	L	0	100/66*	L/H*	L	1
		16	33	L	Н	0	100	L	L	1

<sup>\*</sup> Denotes modified step mode



#### **Pin-out Diagrams**

#### LP Package



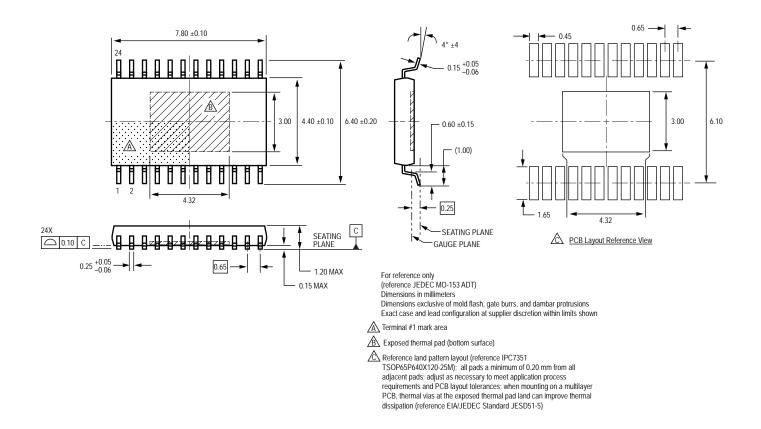
#### **Terminal List Table**

Name	Num- ber	Description			
	LP				
CP1	1	Charge pump capacitor terminal			
CP2	2	Charge pump capacitor terminal			
PH1	14	Logic input			
PH2	23	Logic input			
GND	13, 24	Ground*			
IN02	5	Logic input			
IN12	6	Logic input			
NC	_	No connection			
OUT1A	18	DMOS Full Bridge 1 Output A			
OUT1B	15	DMOS Full Bridge 1 Output B			
OUT2A	19	DMOS Full Bridge 2 Output A			
OUT2B	22	DMOS Full Bridge 2 Output B			
REF	12	G <sub>m</sub> reference voltage input			
IN11	7	Logic input			
ROSC	8	Timing set			
SENSE1	17	Sense resistor terminal for Bridge 1			
SENSE2	20	Sense resistor terminal for Bridge 2			
SLEEP	9	Logic input			
IN01	11	Logic input			
VBB1	16	Load supply			
VBB2	21	Load supply			
VCP	3	Reservoir capacitor terminal			
VDD	10	Logic supply			
VREG	4	Regulator decoupling terminal			
PAD	_	Exposed pad for enhanced thermal dissipation*			

<sup>\*</sup>The GND pins must be tied together externally by connecting to the PAD ground plane under the device.



#### LP Package, 24-Pin TSSOP with Exposed Thermal Pad



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